High Speed Switching Silicon N-channel MOSFET

DESCRIPTION

INK0410AC1 is a Silicon N-channel MOSFET.

This product is most suitable for use such as portable machinery, because of low voltage drive and low on resistance.

FEATURE

- •Input impedance is high, and not necessary to consider a drive electric current.
- *High drain current ID=3.5A
- •Drive voltage 4V
- •Low on Resistance. RDS(ON)= $54m\Omega typ(@VGS=10V)$.
- · High speed switching.

APPLICATION

Switching.

MAXIMUM RATINGS (Ta=25°C)

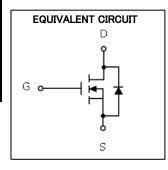
Parameter	Symbol	Rating	Unit	
Drain-Source Voltage	VDSS	60	V	
Gate-Source Voltage	Vgss	±20	٧	
Drain Current(DC) (※1)	ĪD	3.5	Α	
Drain Current(Pulse) (※2)	I DP	7	Α	
Total Power Dissipation (%1)	PD	0.9	W	
Channel Temperature	Tch	+150	°C	
Storage Temperature	Tstg	−55 ~ +150	°C	

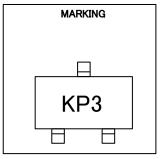
¾1 package mounted on glass-epoxy substrate.

(39mm × 39mm × 1.6mm, Cu pad 1500mm²)

※2 Single pulse Pw≦10ms , Duty cycle≦1%

OUTLINE DRAWING 2.8 0.65 1.5 0.65 1.5 0.65 TERMINAL CONNECTOR 1: GATE 2: SOURCE 2: SOURCE 3: DRAIN Unit: mm



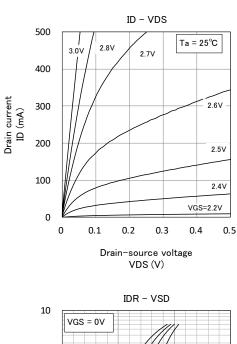


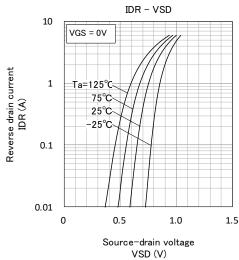
ELECTRICAL CHARACTERISTICS (Ta=25°C)

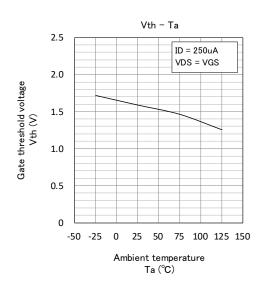
Parameter	Symbol	Test Condition	Limit			Unit
			MIN	TYP	MAX	Unit
Drain-Source Breakdown Voltage	V(BR)DSS	$I_D=250 \mu$ A, $V_{GS}=0V$	60	_	-	٧
Gate-Source Leak Current	Igss	$V_{GS}=\pm 20V$, $V_{DS}=0V$	-	-	±1.0	μΑ
Zero Gate Voltage Drain Current	Idss	V _{DS} =60V, V _{GS} =0V	-	-	1.0	μΑ
Gate Threshold Voltage	Vth	$I_D=250 \mu$ A, $V_{DS}=V_{GS}$	1.0	-	2.5	٧
Static Drain-Source On-State Resistance	Rds(on)	I _D =3.5A, V _{GS} =4.5V	-	59	83	mΩ
		I _D =3.5A, V _{GS} =10V	-	54	71	mΩ
Input Capacitance	Ciss		-	650	-	pF
Output Capacitance	Coss	V_{DS} =10V, V_{GS} =0V, f=1MHz	-	60	-	
Feedback Capacitance	Crss			40	_	
Switching Time	ton	V _{DD} =20V, I _D =200mA, V _{GS} =5V	-	30	-	ns
	toff		-	50	-	

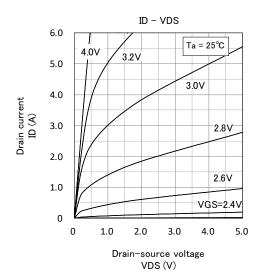
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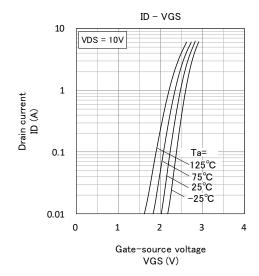
TYPICAL CHARACTERISTICS

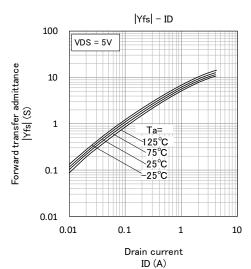




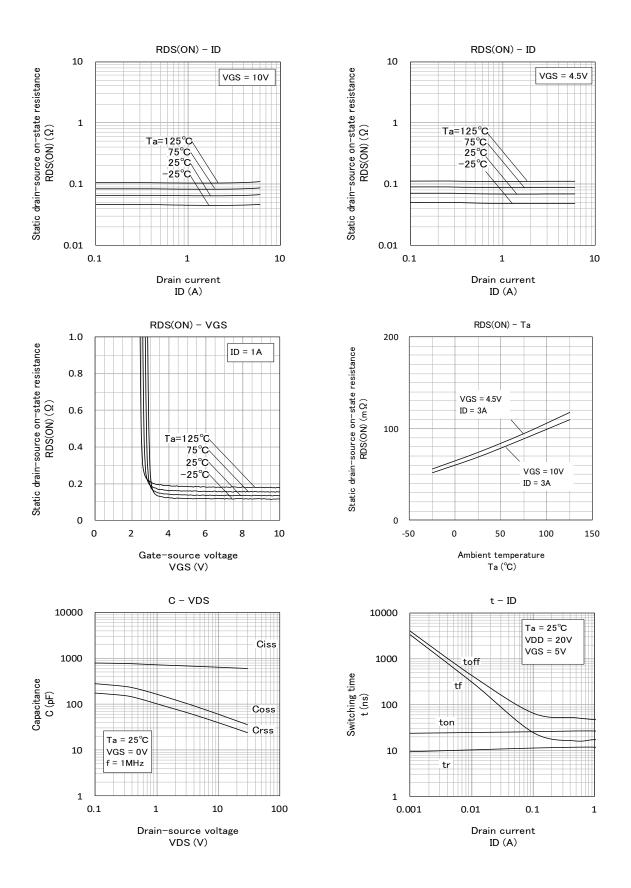




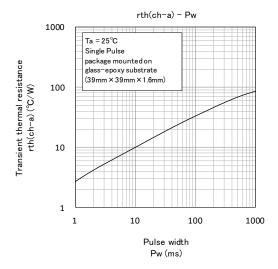


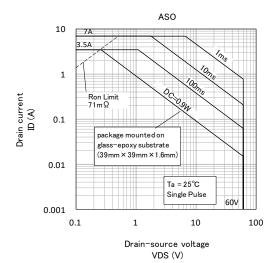


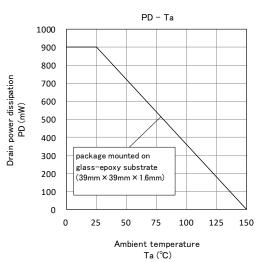
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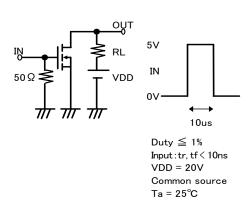
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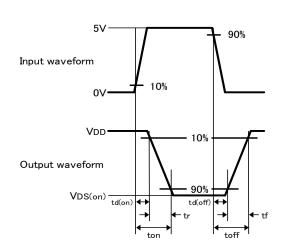






Switching time test condition





Keep safety first in your circuit designs!

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